# M5218AL/P/FP

# **DUAL LOW-NOISE OPERATIONAL AMPLIFIERS (DUAL POWER SUPPLY TYPE)**

#### DESCRIPTION

The M5218 are semiconductor integrated circuits designed for a low noise preamplifier in audio equipment and a general-purpose operational amplifier in other electronic equipment. Two low noise operational amplifier circuits displaying internal phase-compensated high gain and low distortion are contained in an 8-pin SIP, DIP or FP for application over a wide rage as a general-purpose dual amplifier in general electronic equipment.

The devices have virtually the same characteristics as the 4557, 4558, 4559 and 741 operational amplifiers.

The units can also be used as a single power supply type and amplifier in portable equipment. It is also suitable as a headphone amplifier because of its high load current.

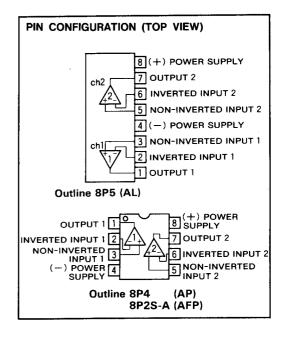
#### **FEATURES**

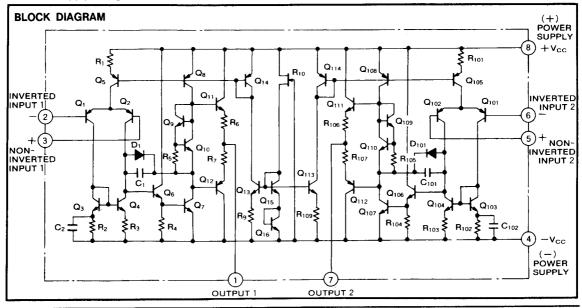
#### **APPLICATION**

General-purpose amplifier in stereo equipment, tape decks, and radio stereo cassette recorders; active filters, servo amplifiers, operational circuits in other general electronic equipment.

# RECOMMENDED OPERATING CONDITINONS

Supply voltage range  $\pm 2 \sim \pm 16 \text{V}$ Rated supply voltage  $\pm 15 \text{V}$ 





# ABSOLUTE MAXIMUM RATINGS ( $T_a=25$ °C, unless otherwise noted)

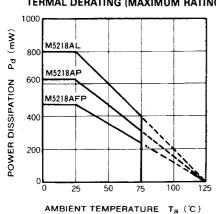
Symbol	Parameter	Conditions Ratings	Unit
V <sub>cc</sub>	Supply voltage	±18	V
ILP	Load current	±50	mA
V <sub>id</sub>	Differential input voltage	±30	V
Vic	Common input voltage	±15	V
Pd	Power dissipation	800(SIP)/625(DIP)/440(FP)	mW
Kθ	Thermal dirating	$T_a \ge 25^{\circ}$ 8(SIP)/6.25(DIP)/4.4(FP)	mW/℃
Topr	Ambient temperature	-20~+75	°C
T <sub>stg</sub>	Storage temperature	_55~+125	°C

# ELECTRICAL CHARACTERISTICS (Ta=25°C, Vcc=±15V)

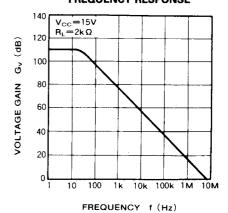
Symbol	Parameter			Limits			
		Test conditions	Min.	Тур.	Max.	Unit	
Icc	Circuit current	V <sub>in</sub> =0		3.0	6.0	mA	
V <sub>IO</sub>	Input offset voltage	R <sub>S</sub> ≤10kΩ		0.5	6.0	mV	
l <sub>io</sub>	Input offset current			5	200	nA	
l <sub>iB</sub>	Input bias current				500	nA	
Rin	Input resistance		0.3	5		МΩ	
Gvo	Open loop voltage gain	$R_L \ge 2k\Omega$ , $V_O = \pm 10V$	86	110		dB	
	Maximum output voltage	R <sub>L</sub> ≥10kΩ	±12	±14		\ \	
V <sub>OM</sub>		R <sub>L</sub> <u>≥</u> 2kΩ	±10	±13			
V <sub>CM</sub>	Common input voltage range		±12	±14		٧	
CMRR	Common mode rejection ratio	R <sub>S</sub> ≦10kΩ	70	90		dB	
SVRR	Sypply voltage	R <sub>S</sub> ≦10kΩ		30	150	μV/V	
Pd	Power dissipation			90	180	mW	
SR	Slew rate	$G_V=0$ dB, $R_L=2k\Omega$		3.0		V/μs	
f <sub>T</sub>	Gain bandwidth product			7		MHz	
V <sub>NI</sub>	Input referred noise voltage	R <sub>S</sub> =1kΩ, BW:10Hz~30kHz		2.0		μVrms	

# TYPICAL CHARACTERISTICS

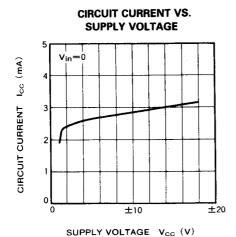
**TERMAL DERATING (MAXIMUM RATING)** 

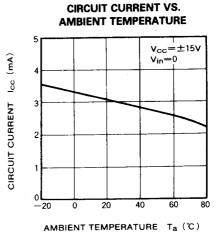


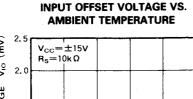
**VOLTAGE GAIN VS.** FREQUENCY RESPONSE

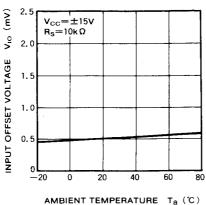


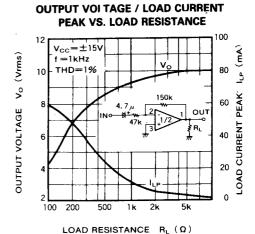


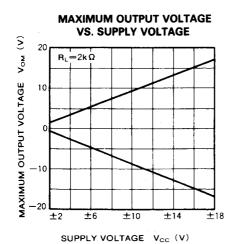


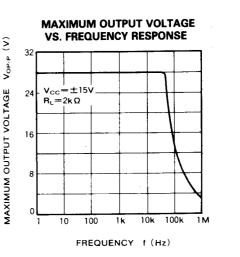






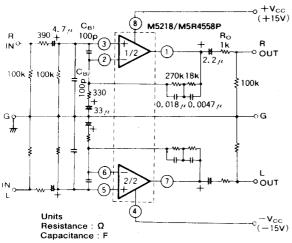






#### APPLICATION EXAMPLES

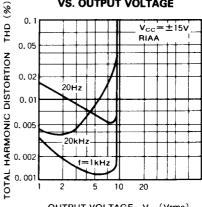
#### (1) Stereo Equalizer amplifier circuit



#### TYPICAL CHARACTERISTICS (Vcc=±15V, RIAA)

- $\cdot G_v = 35.6 dB(f=1kHz)$
- $\cdot$  V<sub>NI</sub>=1/4</sub>Vrms(R<sub>S</sub>=1k $\Omega$ , BW=20Hz $\sim$ 30kHz)
- · Signal-to-noise=72.5dB (IHF-A network, shorted input, 2.5mVrms input sensitivity)
- THD=0.0015%(f=1kHz, V<sub>O</sub>=3Vrms)

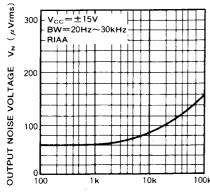
# **TOTAL HARMONIC DISTORTION VS. OUTPUT VOLTAGE**



OUTPUT VOLTAGE Vo (Vrms)

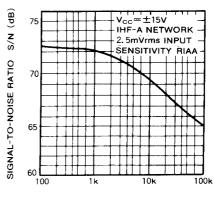
Left channel circuit constants are identical to those of right channel. C<sub>B1</sub>, C<sub>B2</sub>: Capacitors for buzz prevention, use if required. Ro : Resistor used to prevent parasitic oscillation for capacitive loads and current limiting with shorted and other abnormal load conditions.

# **OUTPUT NOISE VOLTAGE VS.** SIGNAL SOURCE RESISTANCE



SIGNAL SOURCE RESISTANCE  $R_S$  (  $\Omega$  )

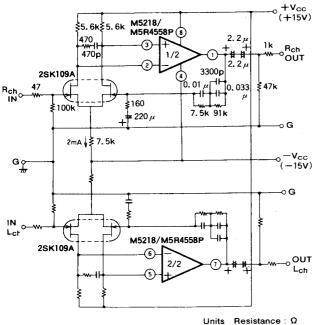
## SIGNAL-TO-NOISE RATIO VS. SIGNAL SOURCE RESISTANCE



SIGNAL SOURCE RESISTANCE  $R_S$  ( $\Omega$ )



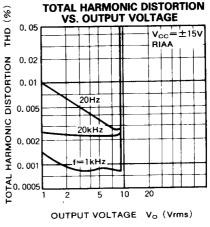
# (2) High S / N stereo DC ICL equalizer



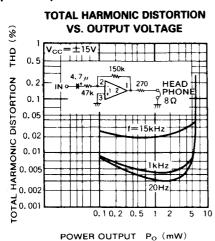
Left channel circuit constants are identical to those of right channel.

# TYPICAL CHARACTERISTICS (Vcc=±15V, RIAA)

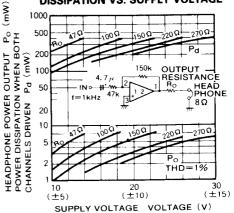
- Signal-to-noise=72.5dB (IHF-A network, shorted input, 2.5mVrms input sensitivity)
- ·  $V_{NI}$ =0.77  $\mu$ Vrms(R<sub>S</sub>=5.1k $\Omega$ , BW=5Hz $\sim$ 100kHz)
- $\cdot$  G<sub>v</sub>=35.6dB(f=1kHz)



### (3) Headphone amplifier



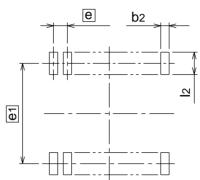
# (Output resistance R<sub>O</sub> is made the parameter) POWER OUTPUT / POWER DISSIPATION VS. SUPPLY VOLTAGE





Capacitance : F

Recomm  Symbol  A  A1  A2  B  B  C  Detail F  Detail F	[	EIAJ Package Code SOP8-P-225-1.27	JEDEC Code	Weight(g)	Lead Material	
Recomm  Symbo  A  A1  A2  b  C  D  E  E  E  D  D  Detail F	ŀ	SOP8-P-225-1.27	_	0.07	Cu Alloy	
12		# <b>#                    </b>		A A		Recomm $ \begin{array}{c c} \hline A_1 \\ A_2 \\ b \\ \hline C \\ \hline D \\ E \\ \hline e \\ HE \\ L \\ L_1 \\ C \\ \hline y \\ \theta \\ b2 \\ \hline $



Recommended Mount Pad

Cymbol	Dimension in Millimeters				
Symbol	Min	Nom	Max		
Α	_	_	1.9		
A1	0.05	_	-		
A2	_	1.5	-		
b	0.35	0.4	0.5		
С	0.13	0.15	0.2		
D	4.8	5.0	5.2		
E	4.2	4.4	4.6		
е	_	1.27	ı		
HE	5.9	6.2	6.5		
L	0.2	0.4	0.6		
L1	_	0.9	ı		
у	_	_	0.1		
$\theta$	0°	_	10°		
b2	_	0.76	_		
e1		5.72			
<b>l</b> 2	1.27	_	-		